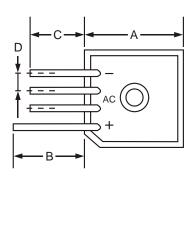


# KBPC15005L THRU KBPC1510L

#### IN - LINE SINGLE - PHASE SILICON BRIDGE RECTIFIER VOLTAGE - 50 TO 1000 VOLTS CURRENT - 15.0 AMPERES



KBPC-L						
Dim	Min	Max				
A	28.45	28.70				
В	19.05	—				
С	13.97	—				
D	5.10	—				
E	10.97	11.23				
G	1.02	—				
Н	3.05	3.60				
J	Metal heat sink					
	epoxy case					
All Dimensions in mm						

### FEATURES

- Surge overload rating 300 amperes peak
- Integrally molded heat-sink provide very low thermal resistance for maximum heat dissipation.
- Universal 3 way terminals: snap-on, wire wrap-around, or P.C. board mounting.
- Plastic package used has Underwriters Laboratory Flammability Classification 94V-0
- High temperature soldering guaranteed: 260°C/10 seconds at 5lbs. (2.3kg) tension

#### **MECHANICAL DATA**

Case: Molded plastic with heatsink integrally mounted in the bridge encapsulation Terminals: wire lead  $\phi$  50 mils.

Weight: 0.65 ounce, 18 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified Sing phase half-wave 60Hz, resistive or inductive load For capacitive load, derate current by 20%

	SYMBOL	KBPC 15005L	KBPC 1501L	KBPC 1502L	KBPC 1504L	KBPC 1506L	KBPC 1508L	KBPC 1510L	UNITS
Maximum Repetitive Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	Vrms	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current T <sub>A</sub> = $55^{\circ}$ C	I(AV)	15.0						Amps	
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	IFSM	300						Amps	
Maximum Instantaneous Forward Voltage Drop Per Bridge Element at 7.5A	VF	VF 1.2						Volts	
Maximum DC Reverse Current $T_A = 25^{\circ}C$ at Rated DC Blocking Voltage $T_A = 125^{\circ}C$	IR	IR 10 500							μA
Rating for fusing (t < 8.3ms)	l <sup>2</sup> t				375				A <sup>2</sup> s
Typical Junction Capacitance (NOTE 1)	CJ				300				pF
Typical Thermal Resistance (NOTE 2)	R	6.3					°C/W		
Operating and Storage Temperature Range	TJ, TSTG	<sub>G</sub> -55 to + 150					°C		

NOTES:

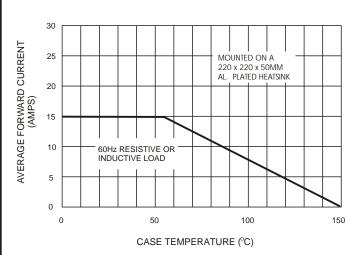
1. Measured at 1.0MHz and applied reverse voltage of 4.0 volts

2. Thermal resistance from junction to case per bridge element

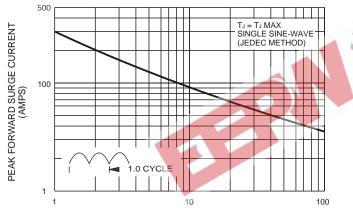
3. Bolt down on heatsink with silicon thermal compound between bridge and mounting surface for maximum heat transfer efficiency with #10 screw

RS

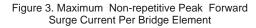
## KBPC15005L THRU KBPC1510L

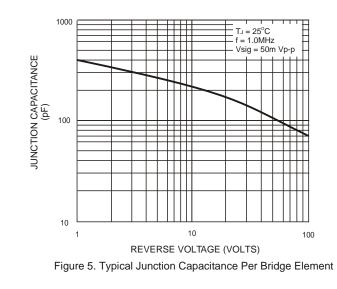


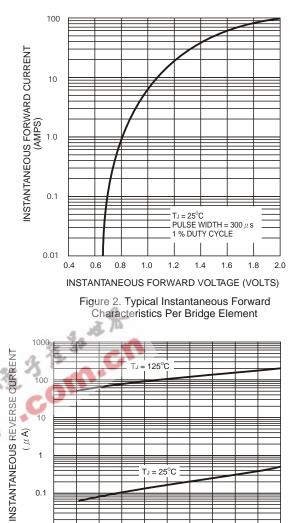




NUMBER OF CYCLES AT 60Hz







PERCENT OF RATED PEAK REVERSE VOLTS (%)

60

80

100

40

0.01

0

20

Figure 4. Typical Reverse Leakage Characteristics Per Bridge Element

